Vishay Semiconductors

TELUX™ LED



DESCRIPTION

The TELUX[™] series is a clear, non diffused LED for high end applications where supreme luminous flux is required.

It is designed in an industry standard 7.62 mm square package utilizing highly developed InGaN technology. The supreme heat dissipation of TELUX[™] allows applications at high ambient temperatures.

All packing units are binned for luminous flux and color to achieve best homogenous light appearance in application.

FEATURES

- Utilizing InGaN technology
- High luminous flux
- Supreme heat dissipation: R_{thJP} is 90 K/W
- High operating temperature: $T_j + 100 \degree C$
- Packed in tubes for automatic insertion
- Luminous flux and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or lightguides
- · Lead (Pb)-free device RoHS compliant
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Compatible with wave solder processes acc. to CECC 00802 and J-STD-020C
- ESD-withstand voltage: up to 1 kV according to JESD22-A114-B
- Automotive qualified

APPLICATIONS

- Exterior lighting
- Dashboard illumination
- Tail-, stop and turn signals of motor vehicles
- Replaces incandescent lamps

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: TELUX™
- Product series: power
- Angle of half intensity: ± 30°

PARTS TABLE					
PART	COLOR, LUMINOUS FLUX	Technology			
VLWW9600	White, $Ø_V > 1500 \text{ mIm}$	InGaN/TAG on SiC			
VLWW9601	White, $Ø_V > 2000 \text{ mlm}$	InGaN/TAG on SiC			



Parameter	Test condition	Symbol	Value	Unit
Reverse voltage 2)	I _R = 10 μA	V _R	5	V
DC Forward current	prward current $T_{amb} \le 50 \text{ °C}$		50	mA
Surge forward current	$t_p \le 10 \ \mu s$	I _{FSM}	0.1	А
Power dissipation		P _V	255	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
$ \begin{array}{c} \mbox{Soldering temperature} \\ \mbox{Soldering temperature} \\ \mbox{t} \leq 5 \mbox{ s, 1.5 mm from body} \\ \mbox{preheat temperature 100 °C/ 30 s} \\ \end{array} $		T _{sd}	260	°C
Thermal resistance junction/ambient	with cathode heatsink of 70 mm ²	R _{thJA}	200	K/W
Thermal resistance junction/pin		R _{thJP}	90	K/W

Note: ¹⁾ $T_{amb} = 25$ °C unless otherwise specified ²⁾ Driving the LED in reverse direction is suitable for a short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLWW960., WHITE							
PARAMETER	TEST CONDITION	SYMBOL	PART	MIN.	TYP.	MAX.	UNIT
Total flux	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 \text{ °K/W}$	Øv	VLWW9600	1500	2200		mlm
Total Ilux			VLWW9601	2000		3600	mlm
Luminous intensity/total flux	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	I _V /Ø _V			0.8		mcd/mlm
Color temperature	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	Τ _K			5500		K
Angle of half intensity	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	φ			± 30		deg
Total included angle	90 % of Total Flux Captured	φ			75		deg
Forward voltage	$I_F = 50 \text{ mA}, \text{ R}_{\text{thJA}} = 200 ^{\circ}\text{K/W}$	V _F			4.3	5.2	V
Reverse voltage	I _R = 10 μA	V _R		5	10		V
Junction capacitance	V _R = 0, f = 1 MHz	Ci			50		pF

Note:

¹⁾ $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified

CHROMATICITY COORDINATE CLASSIFICATION						
GROUP		X		Y		
VLWW9600	VLWW9601	MIN.	MAX.	MIN.	MAX.	
3a		0.2900	0.3025	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
3b		0.3025	0.3150	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
3c		0.2900	0.3025	Y = 1.4x - 0.171	Y = 1.4x - 0.121	
3d		0.3025	0.3150	Y = 1.4x - 0.171	Y = 1.4x - 0.121	
4a		0.3150	0.3275	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
4b		0.3275	0.3400	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
4c	4c	0.3150	0.3275	Y = 1.4x - 0.171	Y = 1.4x - 0.121	
4d	4d	0.3275	0.3400	Y = 1.4x - 0.171	Y = 1.4x - 0.121	
5a		0.3400	0.3525	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
5b		0.3525	0.3650	Y = 1.4x - 0.121	Y = 1.4x - 0.071	
5c	5c	0.3400	0.3525	Y = 1.4x - 0.171	Y = 1.4x - 0.121	
5d	5d	0.3525	0.3650	Y = 1.4x - 0.171	Y = 1.4x - 0.121	

Note:

tolerance ± 0.01



LUMINOUS FLUX CLASSIFICATION					
GROUP	LUMINOUS FLUX (MLM)				
	MIN.	MAX.			
С	1500	2400			
D	2000	3000			
E	2500	3600			
F	3000	4200			

Note:

Luminous flux is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

The above type numbers represent the order grous which include only a few brightness groups. Only one group will be shipped in one tube (there will be no mixing of two groups on each tube).

In order to ensure availability, single brightness groups will not be orderable. In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one tube.

In order to ensure availability, single wavelength groups will not be orderable.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

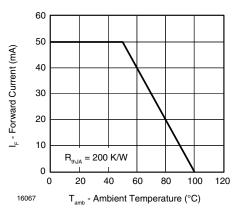
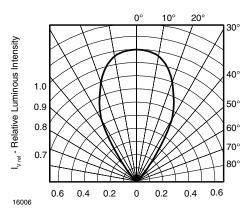
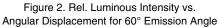


Figure 1. Forward Current vs. Ambient Temperature





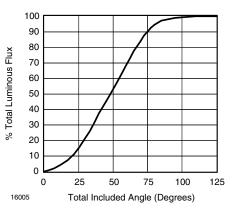


Figure 3. Percentage Total Luminous Flux vs. Total Included Angle for 60° Emission Angle

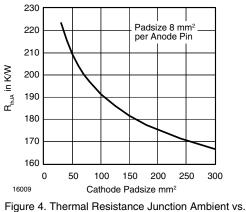


Figure 4. Thermal Resistance Junction Ambient vs. Cathode Padsize

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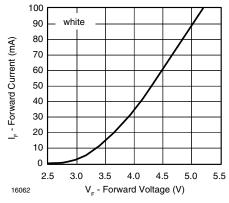


Figure 5. Forward Current vs. Forward Voltage

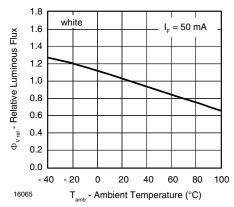


Figure 6. Rel. Luminous Flux vs. Ambient Temperature

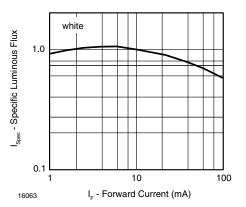


Figure 7. Specific Luminous Flux vs. Forward Current

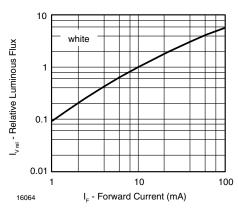


Figure 8. Relative Luminous Flux vs. Forward Current

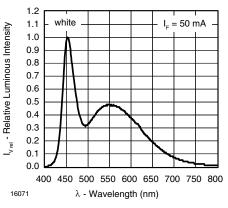


Figure 9. Relative Intensity vs. Wavelength

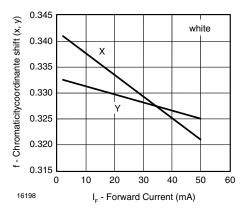


Figure 10. Chromaticity Coordinate Shift vs. Forward Current



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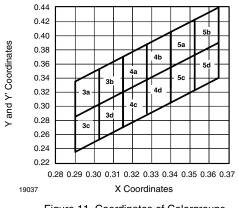
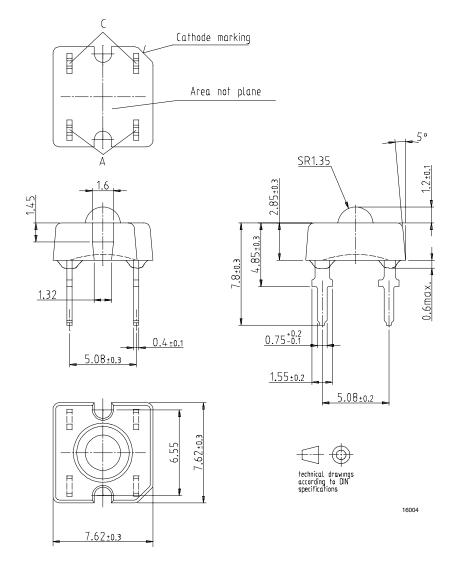


Figure 11. Coordinates of Colorgroups

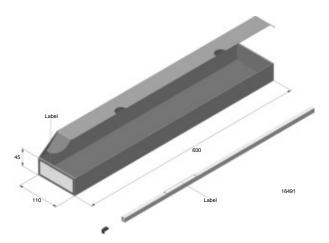
PACKAGE DIMENSIONS in millimeters



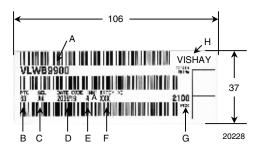
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FAN FOLD BOX Dimensions in millimeters

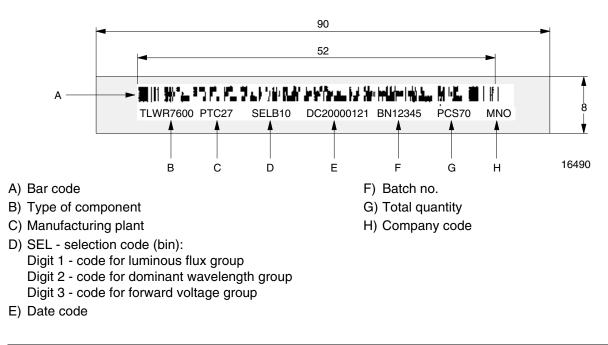


LABEL OF FAN FOLD BOX EXAMPLE:



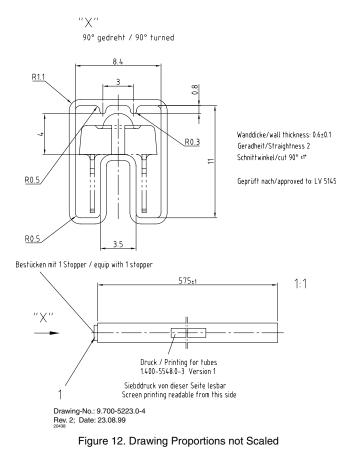
- A) Type of component
- B) Manufacturing plant
- C) SEL selection code (bin):
 - e.g.: A = code for luminous intensity group 4 = code for color group
- D) Date code year/week
- E) Day code (e.g. 4: Thursday, A: early shift)
- F) Batch no.
- G) Total quantity
- H) Company code

EXAMPLE FOR TELUX TUBE LABEL Dimensions in millimeters





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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